TOSHIBA 1SS360

## TOSHIBA DIODE SILICON EPITAXIAL PLANAR TYPE

# 155360

ULTRA HIGH SPEED SWITCHING APPLICATION.

• Small Package

• Low Forward Voltage : V<sub>F</sub>=0.92V (Typ.)

• Fast Reverse Recovery Time :  $t_{rr} = 1.6 ns$  (Typ.)

• Small Total Capacitance : C<sub>T</sub>=2.2pF (Typ.)

### MAXIMUM RATINGS (Ta = 25°C)

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CHARACTERISTIC	SYMBOL	RATING	UNIT
Maximum (Peak) Reverse Voltage	$ m v_{RM}$	85	V
Reverse Voltage	$V_{\mathbf{R}}$	80	V
Maximum (Peak) Forward Current	$I_{\mathbf{FM}}$	300*	mA
Average Forward Current	$I_{O}$	100*	mA
Surge Current (10ms)	$I_{ ext{FSM}}$	2*	A
Power Dissipation	P	100	mW
Junction Temperature	$T_{ m j}$	125	°C
Storage Temperature	$T_{ m stg}$	-55~125	°C

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Unit in mm

Weight: 2.4mg

\* Unit Rating. Total Rating=Unit Rating×1.5

#### ELECTRICAL CHARACTERISTICS (Ta = 25°C)

ELECTRICAL CHARACTERISTICS (TO = 25 C)								
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT		
Forward Voltage	V <sub>F (1)</sub>	$I_{\mathbf{F}} = 1 \text{mA}$	_	0.61	_	v		
	$V_{F(2)}$	$I_{\mathbf{F}} = 10 \text{mA}$		0.74				
	$V_{F(3)}$	$I_{\mathbf{F}} = 100 \text{mA}$	_	0.92	1.20			
Reverse Currunt $ \frac{I_{R(1)}}{I_{R(2)}} $	I <sub>R (1)</sub>	$V_R=30V$	_	_	0.1	$\mu$ <b>A</b>		
	I <sub>R (2)</sub>	$V_R = 80V$	_	_	0.5			
Total Capacitance	$\mathrm{C}_{\mathbf{T}}$	$V_R = 0$ , $f = 1MHz$	_	2.2	4.0	рF		
Reverse Recovery Time	t <sub>rr</sub>	$I_{\mathbf{F}} = 10$ mA, Fig.1	_	1.6	4.0	ns		

## Marking



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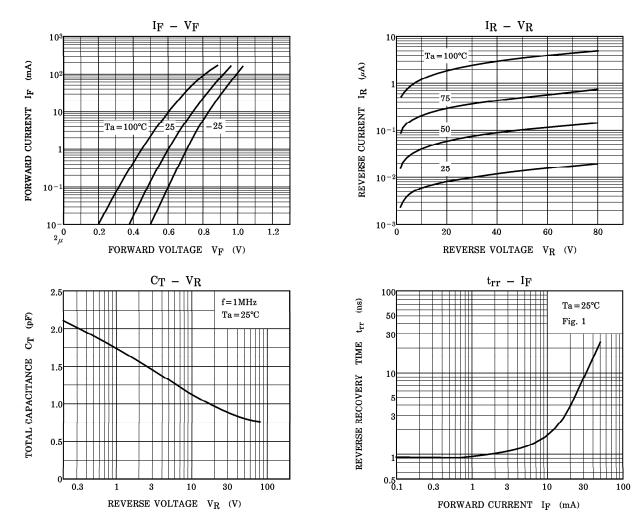
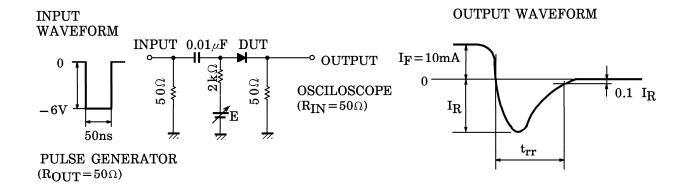


Fig. 1 REVERSE RECOVERY TIME (t<sub>rr</sub>) TEST CIRCUIT



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